

High Power Infrared Emitting Diode, 850 nm, Surface Emitter Technology



LINKS TO ADDITIONAL RESOURCES



DESCRIPTION

As part of the [SurfLight™](#) portfolio, the VSMA1085250 is an infrared, 850 nm emitting diode. It features a double stack emitter chip for highest radiant power. The 42 mil chip size allows 1.5 A DC operation and supports pulsed currents up to 5.0 A.

FEATURES

- Package type: surface-mount
- Package form: high power SMD with lens
- Dimensions (L x W x H in mm): 3.4 x 3.4 x 2.9
- Centroid wavelength: $\lambda_{\text{centroid}} = 850 \text{ nm}$
- Angle of half intensity: $\phi = \pm 28^\circ$
- Designed for high drive currents: up to 1.5 A (DC) and up to 5 A (pulsed)
- Low thermal resistance: $6 \text{ K/W} < R_{\text{thJSP}} < 9 \text{ K/W}$
- ESD: up to 5 kV (according to ANSI / ESDA / JEDEC® JS-001)
- Floor life: 168 h, MSL 3, according to J-STD-020E
- Lead (Pb)-free reflow soldering
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



APPLICATIONS

- Driver and occupant monitoring
- Eye tracking
- Safety and security, CCTV

PRODUCT SUMMARY

| COMPONENT | I_e (mW/sr) at $I_F = 1.0 \text{ A}$ | ϕ (°) | λ_p (nm) | $\lambda_{\text{centroid}}$ (nm) | t_r (ns) |
|-------------|--|------------|------------------|----------------------------------|------------|
| VSMA1085250 | 1350 | ± 28 | 860 | 850 | 10 |

Note

- Test conditions see table “Basic Characteristics”

ORDERING INFORMATION

| ORDERING CODE | PACKAGING | REMARKS | PACKAGE FORM |
|---------------|---------------|----------------------------|----------------------|
| VSMA1085250 | Tape and reel | MOQ: 600 pcs, 600 pcs/reel | High power with lens |

Note

- MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified) | | | | |
|--|---|------------------|-------------|--------------------|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
| Reverse voltage | | V_R | 5 | V |
| Forward current | | I_F | 1.5 | A |
| Surge forward current | $t_p = 100\text{ }\mu\text{s}$ | I_{FSM} | 5 | A |
| Power dissipation | | P_V | 5.33 | W |
| Junction temperature | | T_j | 145 | $^{\circ}\text{C}$ |
| Ambient temperature range | | T_{amb} | -40 to +125 | $^{\circ}\text{C}$ |
| Storage temperature range | | T_{stg} | -40 to +125 | $^{\circ}\text{C}$ |
| Soldering temperature | According to Fig. 11, J-STD-020E | T_{sd} | 260 | $^{\circ}\text{C}$ |
| Thermal resistance junction to solder point real ⁽¹⁾ | JESD 51 | $R_{thJSP,real}$ | 6 to 9 | K/W |
| Thermal resistance junction to ambient real | JESD 51 | $R_{thJA,real}$ | 150 | K/W |
| ESD sensitivity | According to ANSI / ESDA / JEDEC JS-001 | V_{ESD} | 5 | kV |

Note

- (1) Thermal resistance junction to solder point real has been measured with the part mounted on an ideal heatsink and the optical output power has been deducted from the total electrical power dissipation

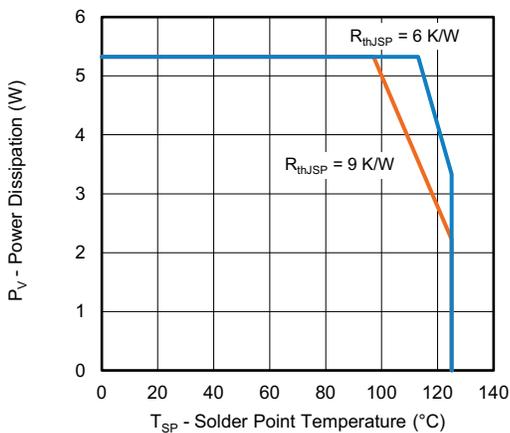


Fig. 1 - Power Dissipation Limit vs. Solder Point Temperature

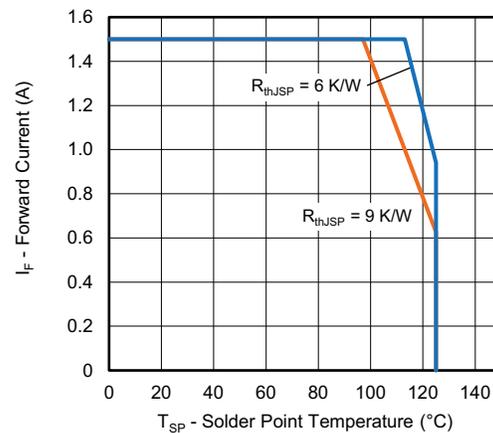


Fig. 2 - Forward Current Limit vs. Solder Point Temperature



| BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | |
|--|---|-----------------------------|------------------------------------|-------|------|-------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Forward voltage | I _F = 0.35 A, t _p = 10 ms | V _F | 2.7 | 2.95 | 3.1 | V |
| | I _F = 1 A, t _p = 100 μs | V _F | 2.8 | 3.1 | 3.3 | V |
| | I _F = 1.5 A, t _p = 100 μs | V _F | 2.9 | 3.25 | 3.55 | V |
| | I _F = 5 A, t _p = 100 μs | V _F | 3.2 | 3.9 | 4.4 | V |
| Temperature coefficient of V _F | I _F = 1 A, t _p = 200 μs | | - | -2 | - | mV/K |
| Reverse current | | I _R | Not designed for reverse operation | | | μA |
| Radiant intensity | I _F = 0.35 A, t _p = 10 ms | I _e | 400 | 500 | 600 | mW/sr |
| | I _F = 1 A, t _p = 100 μs | I _e | 1000 | 1350 | 1700 | mW/sr |
| | I _F = 1.5 A, t _p = 100 μs | I _e | 1400 | 1950 | 2500 | mW/sr |
| | I _F = 5 A, t _p = 100 μs | I _e | 4250 | 6000 | 7750 | mW/sr |
| Radiant power | I _F = 1 A, t _p = 100 μs | φ _e | - | 1425 | - | mW |
| | I _F = 1.5 A, t _p = 100 μs | φ _e | - | 2100 | - | mW |
| Temperature coefficient of φ | I _F = 1 A, t _p = 200 μs | TK _φ | - | -0.15 | - | %/K |
| Angle of half intensity | | φ | - | ± 28 | - | ° |
| Peak wavelength | I _F = 1 A, t _p = 300 μs | λ _p | - | 860 | - | nm |
| Centroid wavelength | I _F = 1 A, t _p = 300 μs | λ _{centroid} | - | 850 | - | nm |
| Spectral bandwidth | I _F = 1 A, t _p = 300 μs | Δλ | - | 30 | - | nm |
| Temperature coefficient of λ _p | I _F = 100 mA, t _p = 20 ms | TK _{λ_p} | - | 0.25 | - | nm/K |
| Rise time | I _F = 1 A | t _r | - | 10 | - | ns |
| Fall time | I _F = 1 A | t _f | - | 15 | - | ns |

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

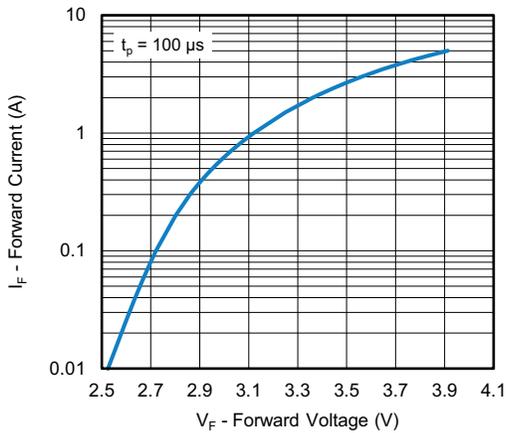


Fig. 3 - Forward Current vs. Forward Voltage

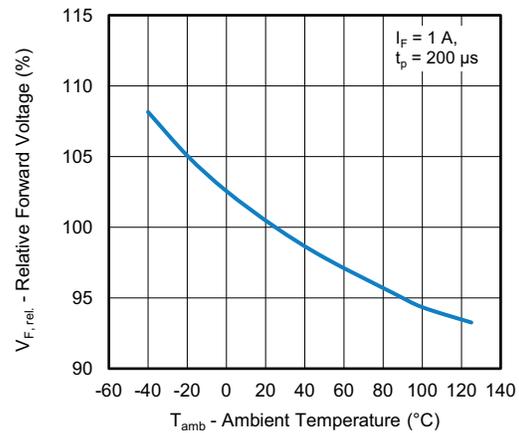


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

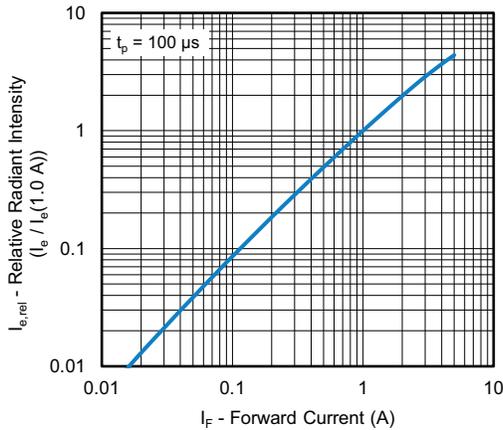


Fig. 5 - Relative Radiant Intensity vs. Forward Current

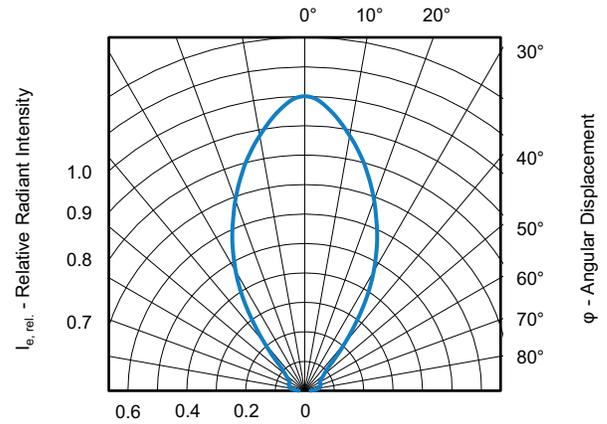


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

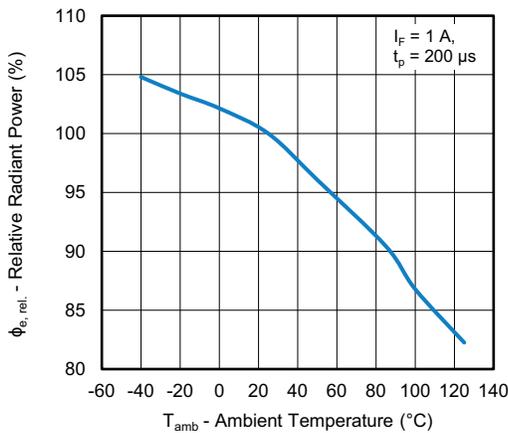


Fig. 6 - Relative Radiant Power vs. Ambient Temperature

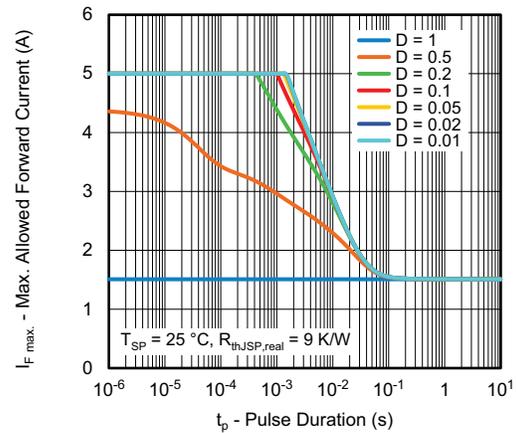


Fig. 9 - Max. Allowed Forward Current vs. Pulse Duration

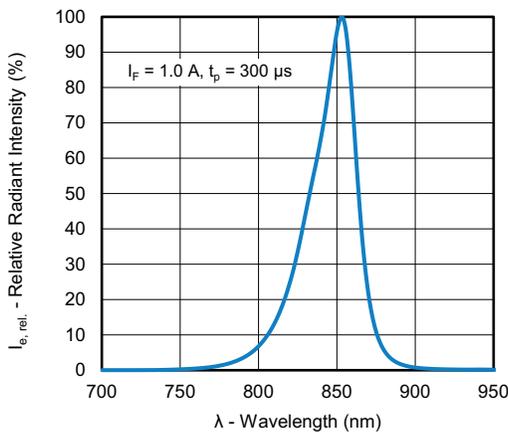


Fig. 7 - Relative Radiant Intensity vs. Wavelength

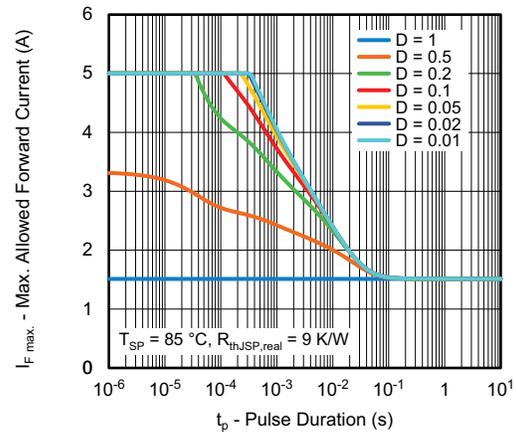
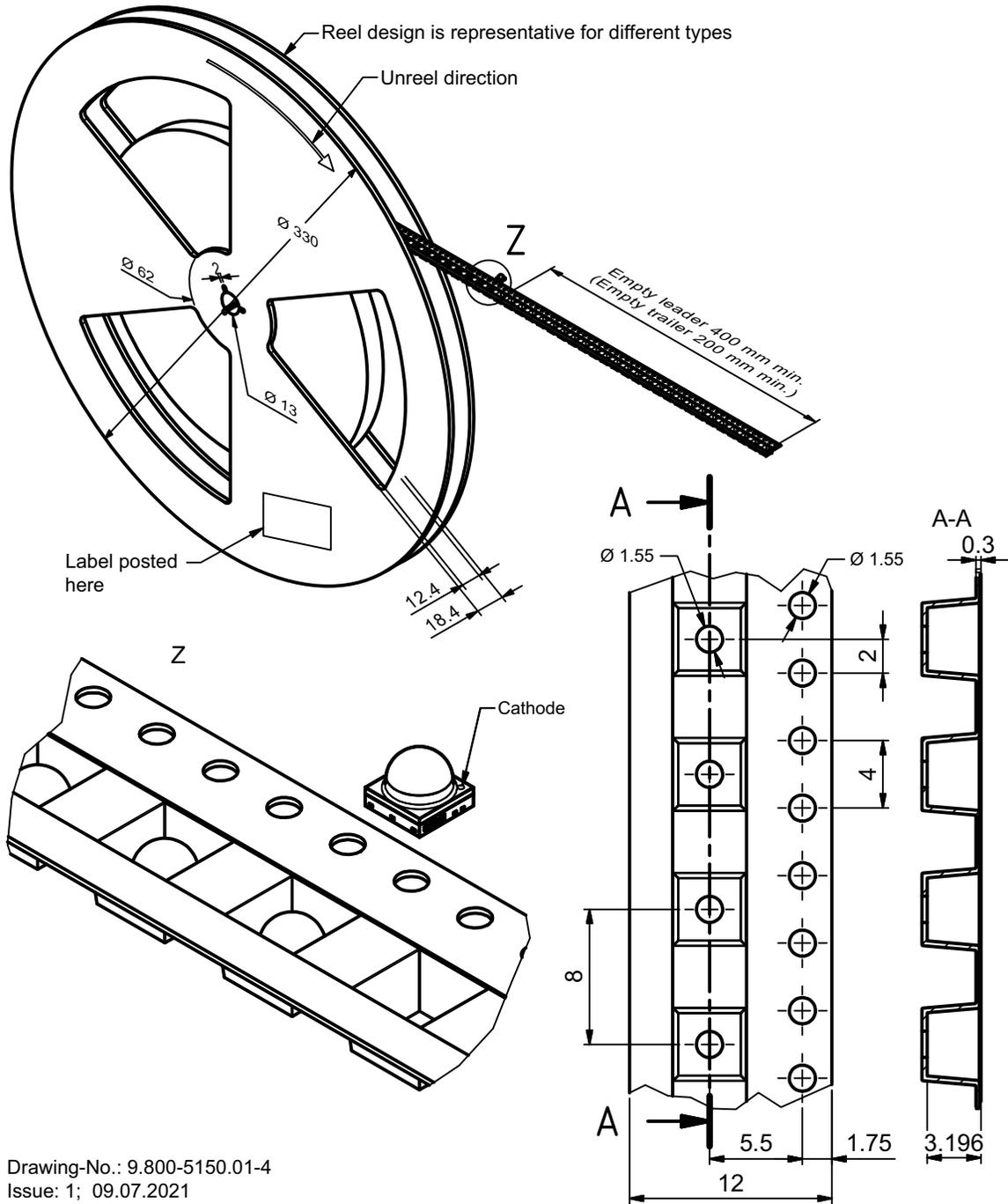


Fig. 10 - Max. Allowed Forward Current vs. Pulse Duration

TAPING DIMENSIONS in millimeters



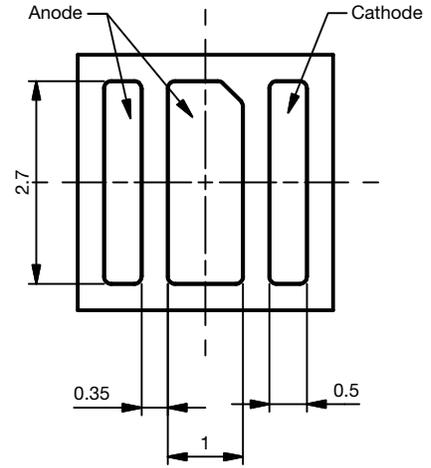
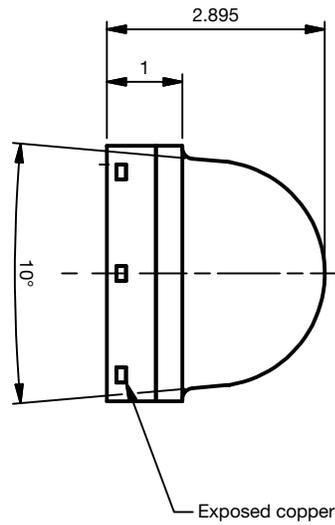
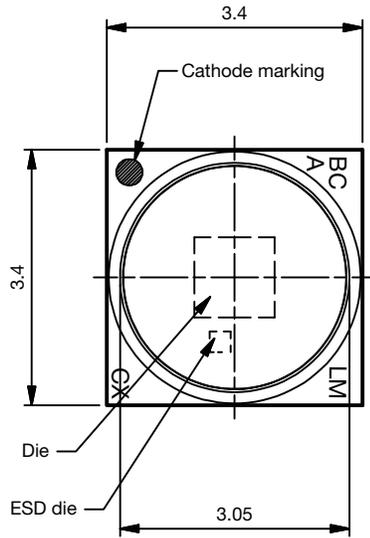
Drawing-No.: 9.800-5150.01-4
Issue: 1; 09.07.2021

Notes

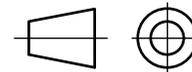
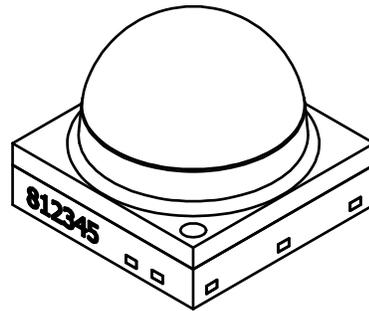
- Empty component pockets sealed with top cover tape
- 7 inch reel - 600 pieces per reel
- The maximum number of consecutive missing lamps is two
- In accordance with ANSI / EIA 481-1-A-1994 specifications



PACKAGE DIMENSIONS in millimeters



Not indicated tolerances ± 0.1



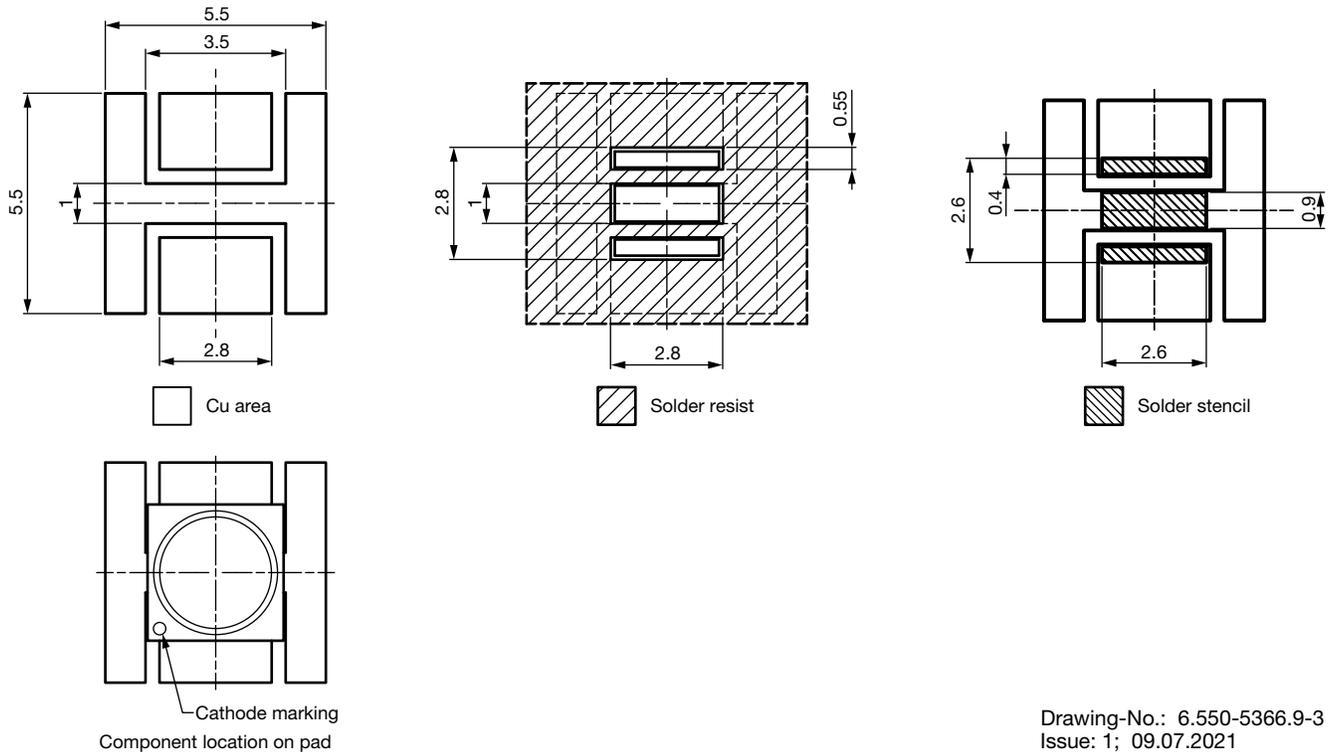
Technical drawings according to DIN specification

Drawing-No.: 6.550-5366.01-4
Issue: 1; 09.07.2021

Notes

- Tolerance is ± 0.10 mm (0.004") unless otherwise noted
- Specifications are subject to change without notice

RECOMMENDED FOOTPRINT



SOLDER PROFILE

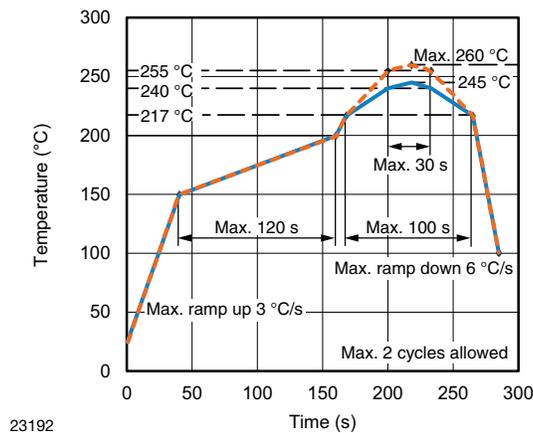


Fig. 11 - Lead (Pb)-free (Sn) Infrared Reflow Solder Profile According to J-STD-020E for Surface-Mount Components

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 168 h

Conditions: $T_{amb} < 30\text{ }^{\circ}\text{C}$, RH < 60 %

Moisture sensitivity level 3, according to J-STD-020E

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-033D or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.



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